National Semiconductor

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5476/DM5476/DM7476 Dual Master-Slave J-K Flip-Flops with Clear, Preset, and Complementary Outputs

General Description

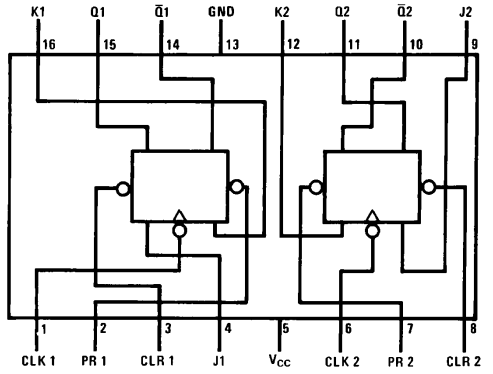
This device contains two independent positive pulse triggered J-K flip-flops with complementary outputs. The J and K data is processed by the flip-flop after a complete clock pulse. While the clock is low the slave is isolated from the master. On the positive transition of the clock, the data from the J and K inputs is transferred to the master. While the clock is high the J and K inputs are disabled. On the negative transition of the clock, the data from the master is transferred to the slave. The logic state of J and K inputs must not be allowed to change while the clock is high. The data is transfered to the outputs on the falling edge of the clock pulse. A low logic level on the preset or clear inputs will set or reset the outputs regardless of the logic levels of the other inputs.

Features

- Alternate Military/Aerospace device (5476) is available. Contact a National Semiconductor Sales Office/Distributor for specifications.

Connection Diagram

Dual-In-Line Package



TL/F/6528–1

Order Number 5476DMQB, 5476FMQB, DM5476J, DM5476W or DM7476N
See NS Package Number J16A, N16E or W16A

Function Table

Inputs					Outputs	
PR	CLR	CLK	J	K	Q	$\overline{Q}$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H*	H*
H	H	⊓⊔	L	L	Q_0	$\overline{Q}_0$
H	H	⊓⊔	H	L	H	L
H	H	⊓⊔	L	H	L	H
H	H	⊓⊔	H	H	Toggle	

H = High Logic Level

L = Low Logic Level

X = Either Low or High Logic Level

⊓⊔ = Positive pulse data. The J and K inputs must be held constant while the clock is high. Data is transfered to the outputs on the falling edge of the clock pulse.

* = This configuration is nonstable; that is, it will not persist when the preset and/or clear inputs return to their inactive (high) level.

Q_0 = The output logic level before the indicated input conditions were established.

Toggle = Each output changes to the complement of its previous level on each complete active high level clock pulse.

RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	5.5V
Operating Free Air Temperature Range	
DM54 and 54	−55°C to +125°C
DM74	0°C to +70°C
Storage Temperature Range	−65°C to +150°C

Note: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Recommended Operating Conditions

Symbol	Parameter		DM5476			DM7476			Units
			Min	Nom	Max	Min	Nom	Max	
V_{CC}	Supply Voltage		4.5	5	5.5	4.75	5	5.25	V
V_{IH}	High Level Input Voltage		2			2			V
V_{IL}	Low Level Input Voltage				0.8			0.8	V
I_{OH}	High Level Output Current				−0.4			−0.4	mA
I_{OL}	Low Level Output Current				16			16	mA
f_{CLK}	Clock Frequency (Note 6)		0		15	0		15	MHz
t_W	Pulse Width (Note 6)	Clock High	20			20			ns
		Clock Low	47			47			
		Preset Low	25			25			
		Clear Low	25			25			
t_{SU}	Input Setup Time (Notes 1 & 6)		0 ↑			0 ↑			ns
t_H	Input Hold Time (Notes 1 & 6)		0 ↓			0 ↓			ns
T_A	Free Air Operating Temperature		−55		125	0		70	°C

Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 2)	Max	Units
V_I	Input Clamp Voltage	V_{CC} = Min, I_I = −12 mA				−1.5	V
V_{OH}	High Level Output Voltage	V_{CC} = Min, I_{OH} = Max V_{IL} = Max, V_{IH} = Min		2.4	3.4		V
V_{OL}	Low Level Output Voltage	V_{CC} = Min, I_{OL} = Max V_{IH} = Min, V_{IL} = Max			0.2	0.4	V
I_I	Input Current @ Max Input Voltage	V_{CC} = Max, V_I = 5.5V				1	mA
I_{IH}	High Level Input Current	V_{CC} = Max V_I = 2.4V	J, K			40	μA
			Clock			80	
			Clear			80	
			Preset			80	
I_{IL}	Low Level Input Current	V_{CC} = Max V_I = 0.4V (Note 5)	J, K			−1.6	mA
			Clock			−3.2	
			Clear			−3.2	
			Preset			−3.2	
I_{OS}	Short Circuit Output Current	V_{CC} = Max (Note 3)	DM54	−20		−55	mA
			DM74	−18		−55	
I_{CC}	Supply Current	V_{CC} = Max (Note 4)			18	34	mA

Note 1: The symbol (↑, ↓) indicates the edge of the clock pulse is used for reference (↑) for rising edge, (↓) for falling edge.

Note 2: All typicals are at V_{CC} = 5V, T_A = 25°C.

Note 3: Not more than one output should be shorted at a time.

Note 4: With all outputs open, I_{CC} is measured with the Q and $\overline{Q}$ outputs high in turn. At the time of measurement the clock input is grounded.

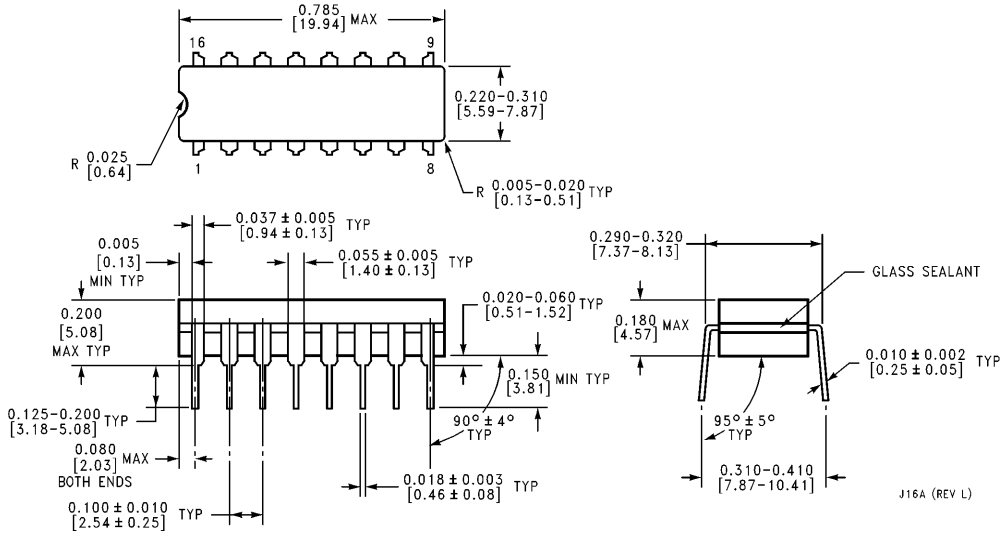
Note 5: Clear is measured with preset high and preset is measured with clear high.

Note 6: T_A = 25°C and V_{CC} = 5V.

Switching Characteristics at $V_{CC} = 5V$ and $T_A = 25°C$ (See Section 1 for Test Waveforms and Output Load)

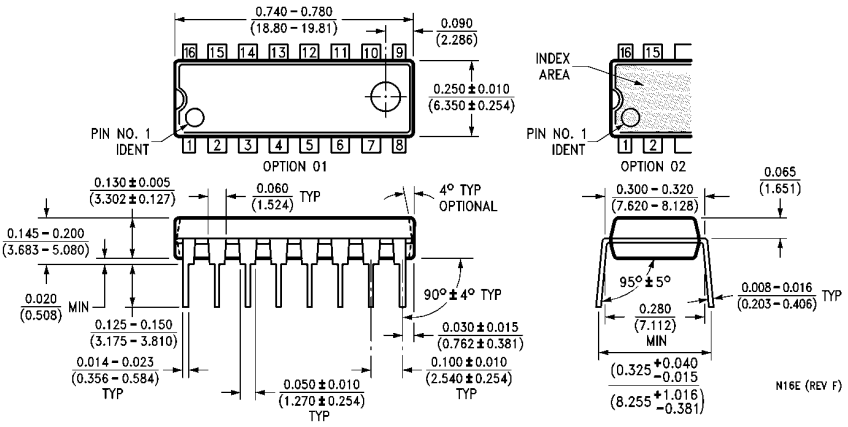
Symbol	Parameter	From (Input) To (Output)	$R_L = 400\Omega$ $C_L = 15$ pF		Units
			Min	Max	
f_{MAX}	Maximum Clock Frequency		15		MHz
t_{PHL}	Propagation Delay Time High to Low Level Output	Preset to $\overline{Q}$		40	ns
t_{PLH}	Propagation Delay Time Low to High Level Output	Preset to Q		25	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Clear to Q		40	ns
t_{PLH}	Propagation Delay Time Low to High Level Output	Clear to $\overline{Q}$		25	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Clock to Q or $\overline{Q}$		40	ns
t_{PLH}	Propagation Delay Time Low to High Level Output	Clock to Q or $\overline{Q}$		25	ns

Physical Dimensions inches (millimeters)

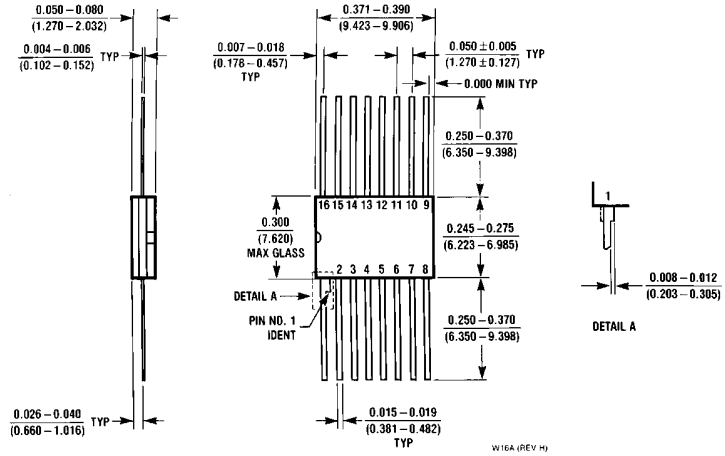


16-Lead Ceramic Dual-In-Line Package (J)
Order Number 5476DMQB or DM5476J
NS Package Number J16A

Physical Dimensions inches (millimeters) (Continued)



16-Lead Molded Dual-In-Line Package (N)
Order Number DM7476N
NS Package Number N16E



16-Lead Ceramic Flat Package (W)
Order Number 5476FMQB or DM7476W
NS Package Number W16A

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National Semiconductor Corporation
1111 West Bardin Road
Arlington, TX 76017
Tel: 1(800) 272-9959
Fax: 1(800) 737-7018

National Semiconductor Europe
Fax: (+49) 0-180-530 85 86
Email: cnjwge@tevm2.nsc.com
Deutsch Tel: (+49) 0-180-530 85 85
English Tel: (+49) 0-180-532 78 32
Français Tel: (+49) 0-180-532 93 58
Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd.
Tsimshatsui, Kowloon
Hong Kong
Tel: (852) 2737-1600
Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
Tel: 81-043-299-2309
Fax: 81-043-299-2408